

DOCKET NO.: 239120US0DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
KAZUHITO MATSUKAWA : ATTN: APPLICATION DIVISION
SERIAL NO: NEW U.S. PCT APPLN. :
(Divisional of 09/668,368)
FILED: HERewith :
FOR: SEMICONDUCTOR SUBSTRATE, :
SEMICONDUCTOR DEVICE, AND :
MANUFACTURING METHOD :
THEREOF :

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS,
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Discussion of the Amendment begins on page 4 of this paper.

Remarks begins on page 5 of this paper.